

CentralTM Semiconductor Corp.

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Manufacturers of World Class Discrete Semiconductors

CR6A4GPP SERIES

GLASS PASSIVATED JUNCTION
GENERAL PURPOSE SILICON RECTIFIER
6.0 AMP, 400 THRU 1000 VOLTS

CASE 106

FEATURES:

- 6 Amps at $T_A = 60^\circ\text{C}$, 3/8" Lead Length
- Glass Passivated Chip
- Compression Molded Epoxy
- Superior Solvent Resistance
- 400 Amps Surge Current
- Reliable Internal Construction
- Extensive Temperature Range

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CR6A4GPP Series types are 6.0 Amp Glass Passivated Junction Silicon Rectifiers which are high quality, well constructed, highly reliable components designed for use in all types of military, commercial, industrial, entertainment, computer, and automotive applications. **THIS DEVICE IS MANUFACTURED WITH A GLASS PASSIVATED CHIP FOR OPTIMUM RELIABILITY.**

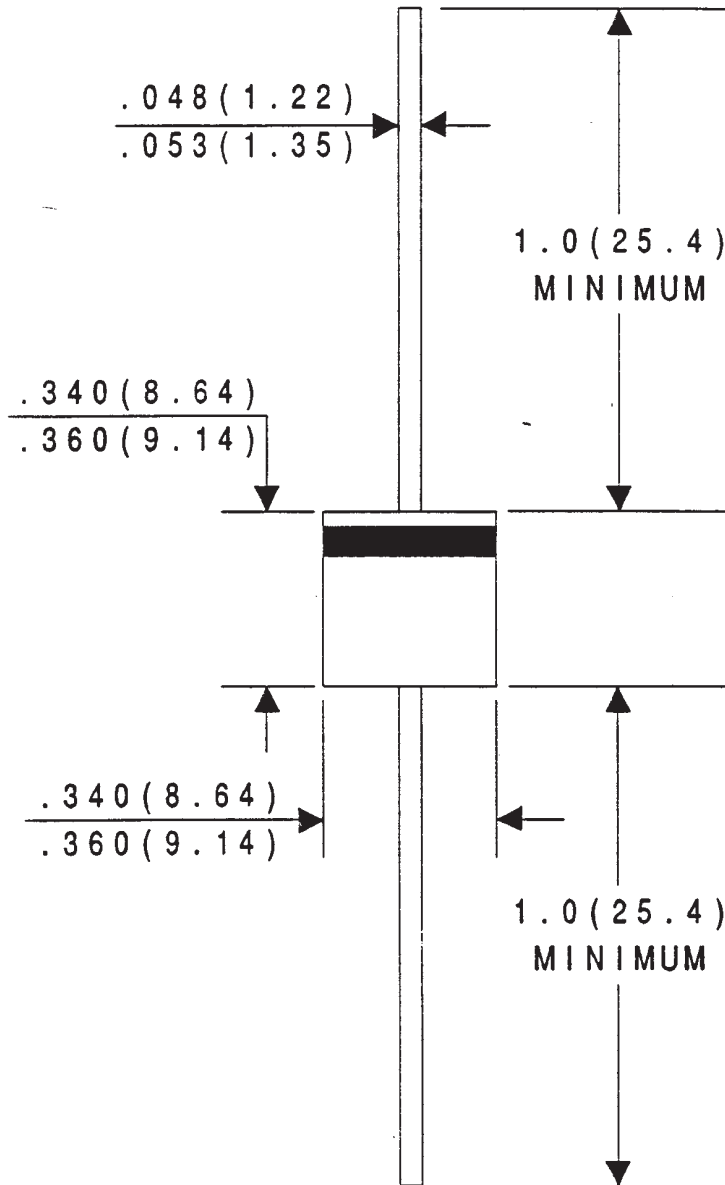
MAXIMUM RATINGS: ($T_A = 25^\circ\text{C}$ unless otherwise noted)

	<u>SYMBOL</u>	<u>CR6A4</u> <u>GPP</u>	<u>CR6A6</u> <u>GPP</u>	<u>CR6A8</u> <u>GPP</u>	<u>CR6A10</u> <u>GPP</u>	<u>UNITS</u>
Peak Repetitive Reverse Voltage	V_{RRM}	400	600	800	1000	V
DC Blocking Voltage	V_R	400	600	800	1000	V
RMS Reverse Voltage	$V_{R(RMS)}$	280	420	560	700	V
Average Forward Current						
@ $T_A = 60^\circ\text{C}$	I_O		6.0			A
Peak Forward Surge Current	I_{FSM}		400			A
Operating and Storage						
Junction Temperature	T_J, T_{stg}		-65 to +175			$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS: ($T_A = 25^\circ\text{C}$ unless otherwise noted)

<u>SYMBOL</u>	<u>TEST CONDITIONS</u>	<u>MIN</u>	<u>MAX</u>	<u>UNITS</u>
V_F	$I_F = 6.0\text{A}$		1.0	V
I_R	$V_R = \text{Rated } V_{RRM}$		10	μA

CASE 106 - MECHANICAL OUTLINE



All Dimensions in Inches (mm).